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FDB52N20 N-Channel UniFET[™] MOSFET **200 V, 52 A, 49 m**Ω

Features

- $R_{DS(on)}$ = 49 m Ω (Max.) @ V_{GS} = 10 V, I_D = 26 A
- Low Gate Charge (Typ. 49 nC)
- Low C_{rss} (Typ. 66 pF)
- 100% Avalanche Tested

Applications

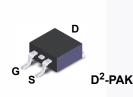
- PDP TV
- Lighting
- · Uninterruptible Power Supply
- AC-DC Power Supply

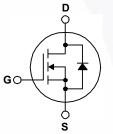




Description

UniFETTM MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

| Symbol | | FDB52N20 | Unit | |
|----------------------------------|--|---|-------------|-----------|
| V _{DSS} | Drain-Source Voltag | 200 | V | |
| ID | Drain Current | - Continuous (T _C = 25°C) - Continuous (T _C = 100°C) | 52 33 | A A |
| I _{DM} | Drain Current | - Pulsed (Note 1) | 208 | А |
| V _{GSS} | Gate-Source voltage | ±30 | V | |
| E _{AS} | Single Pulsed Avalanche Energy (Note 2) | | 2520 | mJ |
| I _{AR} | Avalanche Current (Note 1) | | 52 | А |
| E _{AR} | Repetitive Avalanche Energy (Note 1) | | 35.7 | mJ |
| dv/dt | Peak Diode Recovery dv/dt (Note 3) | | 4.5 | V/ns |
| P _D | Power Dissipation | wer Dissipation (T _C = 25°C) - Derate Above 25°C | | W W/°C |
| T _{J,} T _{STG} | Operating and Storage Temperature Range | | -55 to +150 | °C |
| TL | Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds | | 300 | °C |

Thermal Characteristics

| Symbol | Parameter | FDB52N20 | Unit |
|-----------------------|--|----------|------|
| $R_{\theta JC}$ | Thermal Resistance, Junction-to-Case, Max. | 0.35 | |
| R_{\thetaJA} | Thermal Resistance, Junction-to-Ambient (1 in ² Pad of 2-oz Copper), Max. | 40 | °C/W |
| $R_{	extsf{	heta}JA}$ | Thermal Resistance, Junction-to-Ambient (Minimum Pad of 2-oz Copper), Max. | 62.5 | |

| FDB52N2 |
|----------------------|
| 7 |
| I-Channel |
| UniFET TM |
| MOSFET |

| Part Number Top Mark Pa | | Package | Packing Method | Reel Size | Та | pe Width | Qu | antity | |
|------------------------------------|--|------------------------|----------------------|--|----------|----------|-------|---------|----------|
| FDB52N20TM FDB52N20 D | | | D ² -PAK | Tape and Reel | 330 mm | | 24 mm | 800 |) units |
| Electric | al Chara | acteristics $T_{c} =$ | 25°C unless | otherwise noted. | | | | | |
| Symbol | | Parameter | | Conditions | 5 | Min. | Тур. | Max | Unit |
| Off Charac | teristics | | | | | | | | |
| BV _{DSS} | Drain-Sour | ce Breakdown Voltage | V _{GS} | V _{GS} = 0 V, I _D = 250 μA | | 200 | | | V |
| ΔBV_{DSS} / ΔT_{J} | Breakdowr Coefficient | Noltage Temperature | I _D = | $I_D = 250 \ \mu$ A, Referenced to 25°C | | | 0.2 | | V/°C |
| I _{DSS} | Zero Gate | Voltage Drain Current | | V_{DS} = 200 V, V_{GS} = 0 V V_{DS} = 160 V, T_{C} = 125°C | | | | 1 10 | μΑ μΑ |
| I _{GSSF} | Gate-Body | Leakage Current, Forw | ard V _{GS} | = 30 V, V _{DS} = 0 V | | | | 100 | nA |
| I _{GSSR} | Gate-Body | Leakage Current, Reve | erse V _{GS} | = -30 V, V _{DS} = 0 V | | | | -100 | nA |
| On Charac | teristics | | | | | | | | |
| V _{GS(th)} | Gate Three | Gate Threshold Voltage | | V _{DS} = V _{GS} , I _D = 250 μA | | 3.0 | | 5.0 | V |
| R _{DS(on)} | Static Drain-Source On-Resistance | | V _{GS} | V _{GS} = 10 V, I _D = 26 A | | | 0.041 | 0.049 | Ω |
| 9 _{FS} | Forward Transconductance | | V _{DS} | = 40 V, I _D = 26 A | | - | 35 | | S |
| Dynamic C | haracterist | ics | | | | | • | | |
| C _{iss} | Input Capa | Capacitance | | V _{DS} = 25 V, V _{GS} = 0 V, f = 1.0 MHz | | | 2230 | 2900 | pF |
| C _{oss} | Output Capacitance Reverse Transfer Capacitance | | f = 1 | | | | 540 | 700 | pF |
| C _{rss} | | | | | | | 66 | 100 | pF |
| Switching | Characteris | tics | | | | | | | |
| t _{d(on)} | Turn-On Delay Time | | | $V_{DD} = 100 \text{ V}, \text{ I}_{D} = 52 \text{ A},$ | | | 53 | 115 | ns |
| t _r | Turn-On R | ise Time | V _{GS} | V_{GS} = 10 V, R_{G} = 25 Ω | | | 175 | 359 | ns |
| t _{d(off)} | Turn-Off De | elay Time | | | | | 48 | 107 | ns |
| t _f | Turn-Off Fa | all Time | | | (Note 4) | | 29 | 68 | ns |
| Qg | Total Gate | Charge | V _{DS} | V_{DS} = 160 V, I _D = 52 A, V _{GS} = 10 V (Note 4) | | | 49 | 63 | nC |
| Q _{gs} | Gate-Source | ce Charge | V _{GS} | | | - | 19 | | nC |
| Q _{gd} | Gate-Drain | Charge | | | | | 24 | | nC |
| Drain-Sour | rce Diode C | haracteristics and Max | ximum Rati | ngs | | | | 1 | |
| I _S | 6 Maximum Continuous Drain-Source Dio | | | ward Current | | | | 52 | А |
| I _{SM} | Maximum Pulsed Drain-Source Diode F | | ode Forward | orward Current | | | | 204 | А |
| V _{SD} | Drain-Sour | ce Diode Forward Volta | ige V _{GS} | V _{GS} = 0 V, I _S = 52 A | | | | 1.4 | V |
| t _{rr} | Reverse R | ecovery Time | 00 | = 0 V, I _S = 52 A, | | | 162 | | ns |
| Q _{rr} | Reverse R | ecovery Charge | dl _F /d | lt =100 A/μs | | | 1.3 | | μC |

Notes:

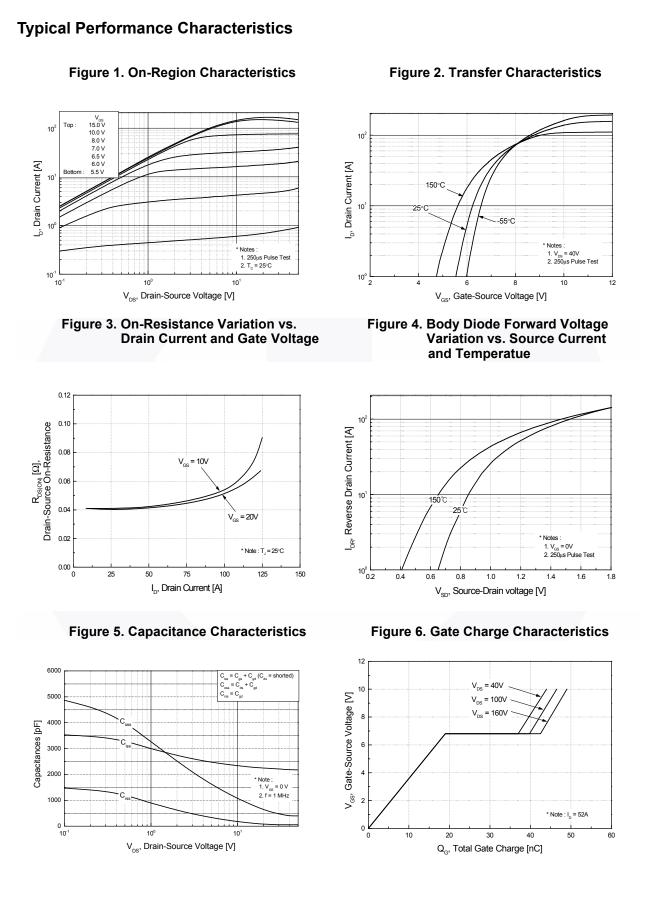
1. Repetitive rating: pulse-width limited by maximum junction temperature.

2. L = 1.4 mH, I_{AS} = 52 A, V_{DD} = 50 V, R_G = 25 Ω , starting T_J = 25°C.

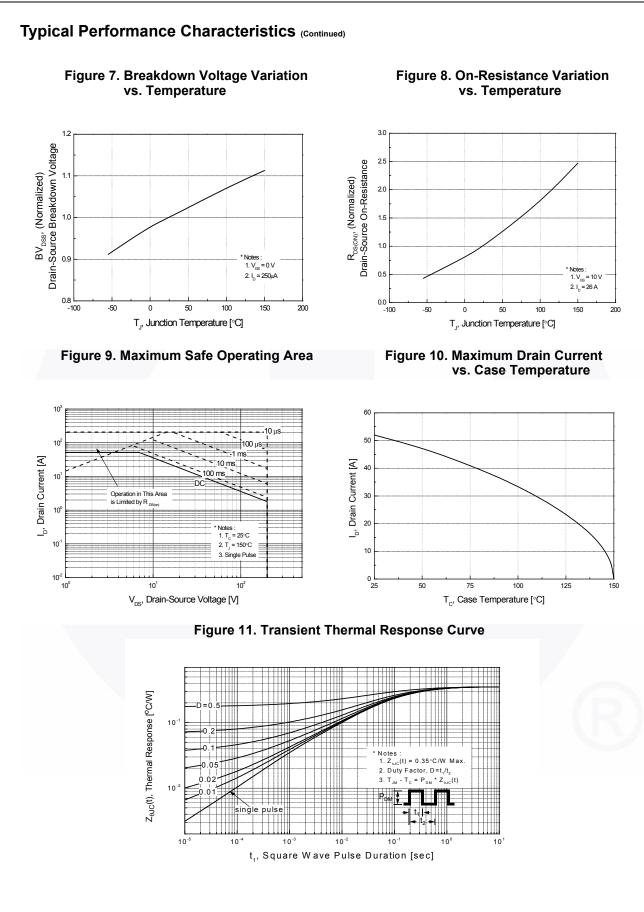
3. I_{SD} \leq 52 A, di/dt \leq 200 A/µs, V_{DD} \leq BV_{DSS}, starting T_J = 25°C.

4. Essentially independent of operating temperature typical characteristics.

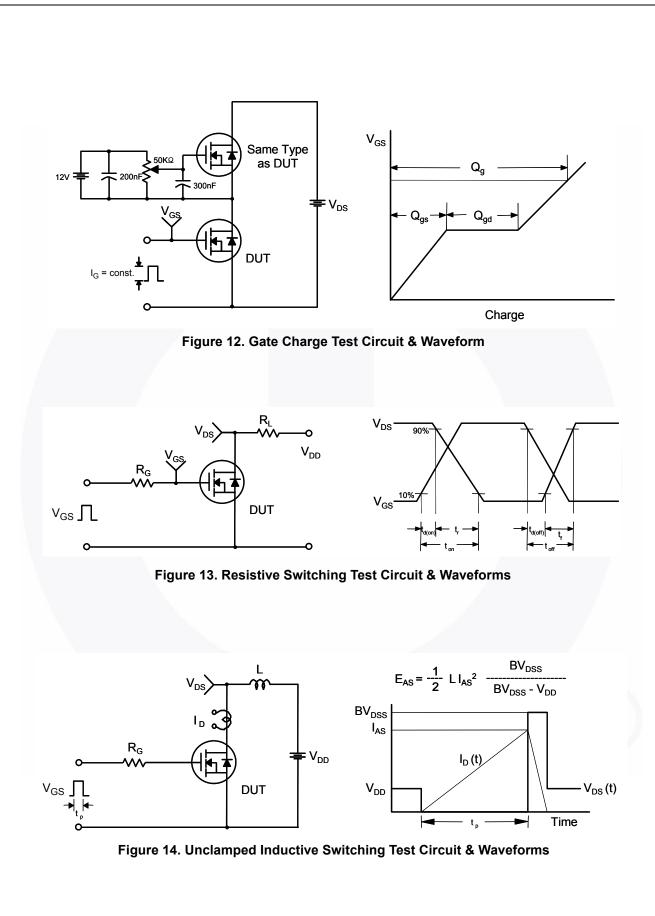
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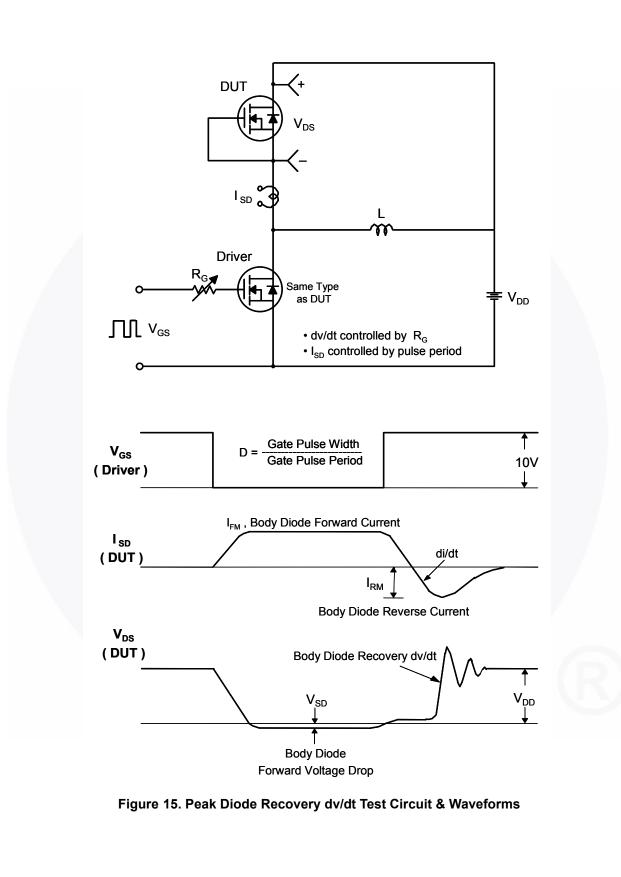


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FDB52N20 — N-Channel UniFETTM MOSFET

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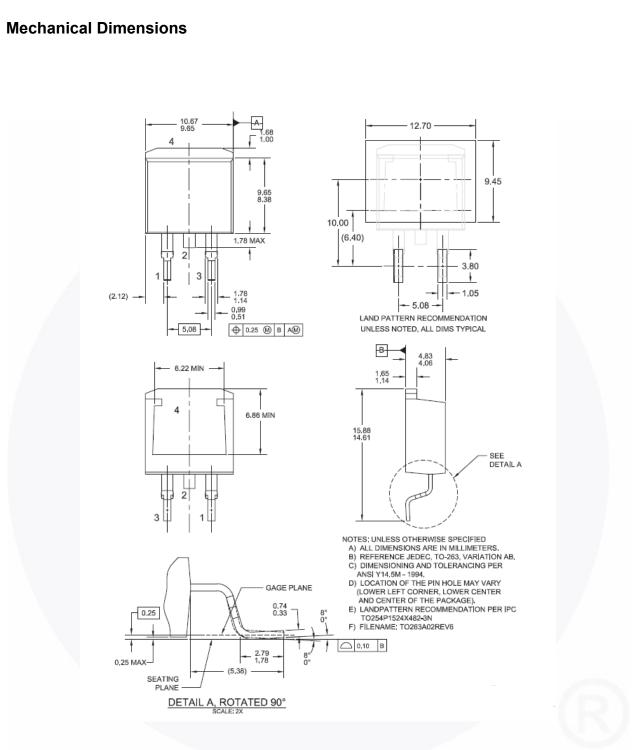


Figure 16. TO263 (D²PAK), Molded, 2-Lead, Surface Mount

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